

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

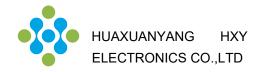
Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

| Ordering Part Number | Package | Marking | |
|-------------------------|---------|------------|--|
| HC1D06065N | QPFN5X6 | HC1D06065N | |







Maximum Ratings (at Tc = 25 °C, unless otherwise specified)

| Parameter | Symbol | Value | Unit | |
|--|------------------|---------------|------------------|--|
| Repetitive Peak Reverse Voltage | V_{RRM} | 650 | V | |
| Surge Peak Reverse Voltage | V_{RSM} | 650 | V | |
| DC Peak Reverse Voltage | V_{R} | 650 | V | |
| Continuous Forward Current $T_{C} = 25^{\circ}C$ $T_{C} = 135^{\circ}C$ $T_{C} = 162^{\circ}C$ | I _F | 23 12 6 | А | |
| Repetitive Peak Forward Surge Current $T_C = 25^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$ $T_C = 110^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$ | I _{FRM} | 28 17 | А | |
| Non-Repetitive Forward Surge Current $T_C = 25^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$ $T_C = 110^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$ | I _{FSM} | 48 43 | А | |
| i^2 dt value $T_C = 25^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$ $T_C = 110^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$ | ∫i²dt | 11.4 9.1 | A ² s | |
| Power dissipation $T_{C} = 25^{\circ}C$ $T_{C} = 110^{\circ}C$ | P _{tot} | 71 30 | W | |
| Operating junction Range | T _j | -55 to +175 | °C | |
| Storage temperature Range | T _{stg} | -55 to +150 | °C | |

Thermal Resistance

| Parameter | Symbol | Тур. | Unit |
|--------------------------------------|------------|------|------|
| Thermal resistance, junction – case. | R_{thJC} | 2.10 | °C/W |



Electrical Characteristic (at Tc = 25 °C, unless otherwise specified)

| Parameter | Symbol | Value | | | l loit | Test Condition |
|-------------------------|----------------|-------|------|------|--------|--|
| | | min. | typ. | max. | Unit | rest Condition |
| Forward Voltage | V _F | | | | | I _F =6A |
| | | - | 1.3 | 1.5 | V | T _j =25°C |
| | | - | 1.5 | | | Т _ј =175°С |
| Reverse Current | I _R | | | | μΑ | V _R =650V |
| | | - | - | 50 | | T _j =25°C |
| | | - | - | 200 | | T _j =175°C |
| Total Capacitive Charge | Q_{C} | ı | 18 | - | nC | V _R =400V, T _j =25℃ |
| | | | | | | $V_{R}=400V, T_{j}=25^{\circ}C$ $Q_{C}=\int_{0}^{V_{R}}C(V)dV$ |
| Total Capacitance | С | | | | pF | T _j =25℃, f=1MHz |
| | | - | 358 | - | | V _R =0V |
| | | - | 36 | - | | V _R =200V V _R =400V |
| | | | 30 | - | | V _R =400V |

Characteristics Curve

Fig 1: Forward Characteristics

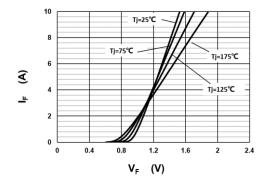


Fig 2: Reverse Characteristics

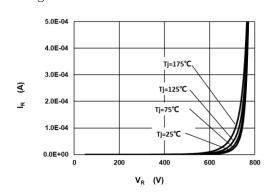


Fig 3: Current Derating

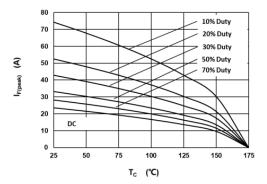


Fig 4: Power Derating

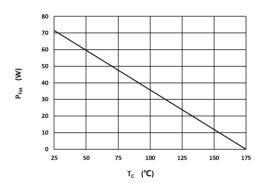


Fig 5: Capacitance vs. Reverse Voltage

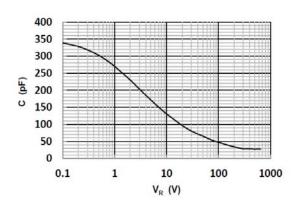


Fig 6: Reverse Charge vs. Reverse Voltage

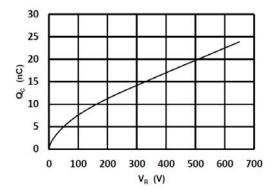
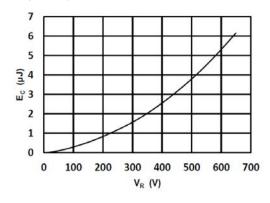


Fig 7: Typical Capacitance Stored Energy



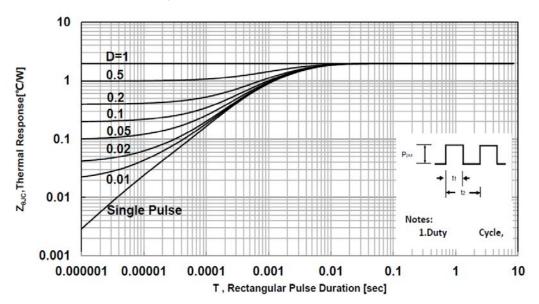
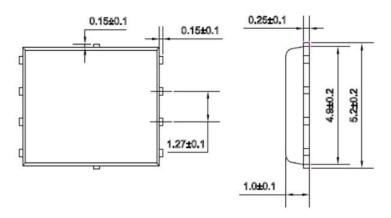
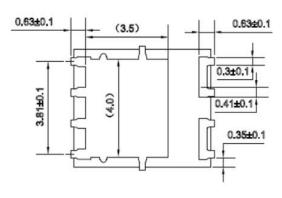


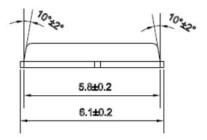
Fig 8: Transient Thermal Impandance

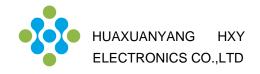
Package Dimensions

Package PQFN5X6









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